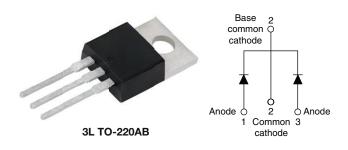
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 15 A



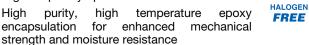
www.vishay.com

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>R</sub>	45 V			
V <sub>F</sub> at I <sub>F</sub>	See Electrical table			
I <sub>RM</sub> max.	100 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	10 mJ			
Package	3L TO-220AB			
Circuit configuration	Common cathode			

### **FEATURES**

High

- 150 °C T<sub>J</sub> operation
- · Low forward voltage drop
- High frequency operation



- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS VALUES				
I <sub>F(AV)</sub>	Rectangular waveform (per device)	30	А		
V <sub>RRM</sub>		35/45	V		
I <sub>FRM</sub>	T <sub>C</sub> = 123 °C (per leg)	30	A		
IFSM	t <sub>p</sub> = 5 μs sine	1020			
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.6	V		
TJ	Range	-65 to +150	°C		

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-MBR3045CT-M3 UNITS					
Maximum DC reverse voltage	V <sub>R</sub>	45	M		
Maximum working peak reverse voltage	V <sub>RWM</sub>	42	V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER SYMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum average forward per leg		$T_{\rm C}$ = 123 °C, rated V <sub>B</sub>		15	
current per device	I <sub>F(AV)</sub>	$T_{\rm C} = 123$ C, fated $V_{\rm R}$		30	1
Peak repetitive forward current per leg	rrent per leg I <sub>FRM</sub> Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 123 °C		30		
Non-repetitive peak surge current	I <sub>ESM</sub>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1020	A
	1 OM	Surge applied at rated load conditions halfwave, single phase, 60 Hz		200	
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 5 mH		10	mJ
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2	А

Revision: 15-Aug-17

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COMPLIANT

# VS-MBR3045CT-M3



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VALUES

0.76

UNITS

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS					
		30 A	T <sub>J</sub> = 25 °C				
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	20 A	T _ 105 °C				
			T <sub>J</sub> = 125 °C				

Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	20 A	20 A T <sub>i</sub> = 125 °C		V
		30 A	1j = 125 C	0.72	
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	$T_J = 25 \ ^\circ C$	Rated DC voltage	1	mA
	IRM (")	T <sub>J</sub> = 125 °C	Haleu DC Vollage	100	
Threshold voltage	V <sub>F(TO)</sub>	$T_{,l} = T_{,l}$ maximum	0.29	V	
Forward slope resistance	r <sub>t</sub>	i j = i j maximum	13.6	mΩ	
Maximum junction capacitance	CT	$V_{R}$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		800	pF
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		-65 to +150	°C		
Maximum storage temperature range	T <sub>Stg</sub>		-65 to +175			
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	1.5			
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased Only for TO-220	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation For D <sup>2</sup> PAK and TO-262	50			
Approximate weight			2	g		
Approximate weight			0.07	oz.		
Mounting torque	num	Non-lubricated threads	6 (5)	kgf ⋅ cm		
Mounting torque maxim	num		12 (10)	(lbf · in)		
Marking device		Case style 3L TO-220AB	MBR3	MBR3045CT		



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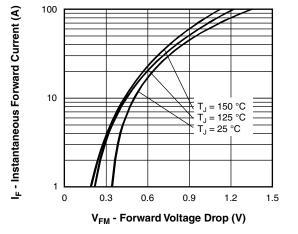


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

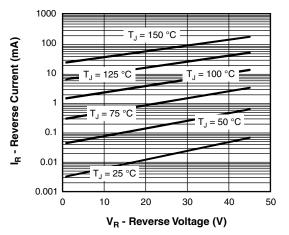


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

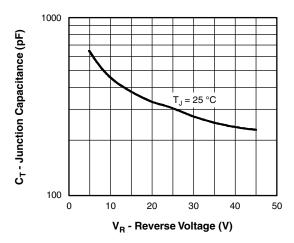
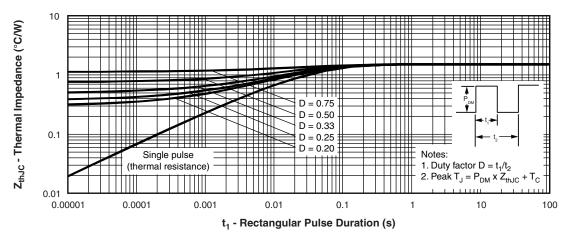
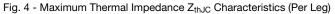


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





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# VS-MBR3045CT-M3

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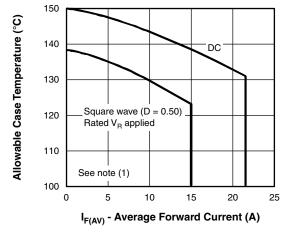


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

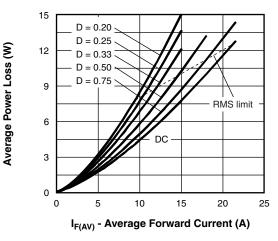


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

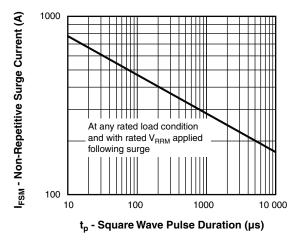


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

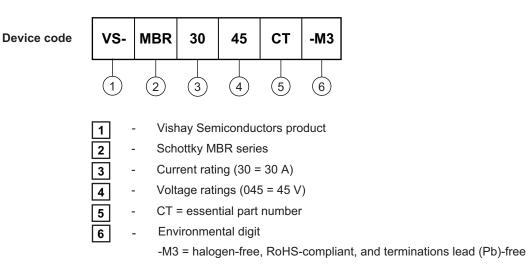
 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd\_{REV} = inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

# VS-MBR3045CT-M3





### **ORDERING INFORMATION TABLE**



 ORDERING INFORMATION (Example)

 PREFERRED P/N
 QUANTITY PER T/R
 MINIMUM ORDER QUANTITY
 PACKAGING DESCRIPTION

 VS-MBR3045CT-M3
 50
 1000
 Antistatic plastic tube

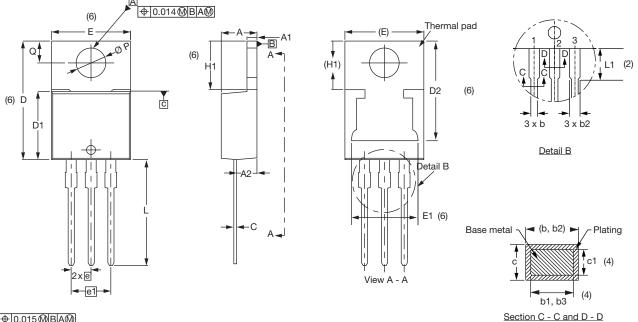
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96154</u>				
Part marking information	www.vishay.com/doc?95028			



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### **3L TO-220AB**

### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	IETERS	INC	NOTES	
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

_		
Conforms to JEDEC <sup>®</sup>	outline	<b>TO-220AB</b>

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STINDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
Е	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØР	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

#### Notes

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

- <sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

Revision: 13-Jun-2019

 $<sup>^{(1)}\,</sup>$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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